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# RoHS EARTH FRIEND

#### **Typical Applications**

The HMC594LC3B is ideal for:

- Fixed Microwave
- Point-to-Multi-Point Radios
- Test & Measurement Equipment
- Radar & Sensors
- Military & Space

#### **Functional Diagram**



# HMC594LC3B

#### GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2 - 4 GHz

#### Features

Gain Flatness: ±0.2 dB Noise Figure: 3 dB Gain: 10 dB Output IP3: +36 dBm DC Supply: +5V @ 95mA / +6V @ 100 mA 50 Ohm Matched Input/Output RoHS Compliant 3x3 mm SMT package

#### **General Description**

The HMC594LC3B is a GaAs pHEMT MMIC Low Noise Amplifier (LNA) which operates from 2 to 4 GHz. The HMC594LC3B features extremely flat performance characteristics including 10 dB of small signal gain, 3 dB of noise figure and output IP3 of +36 dBm across the operating band. This high linearity LNA is ideal for test & measurement equipment and military assemblies due to its compact size, consistent output power and DC blocked RF I/O's. The HMC594LC3B is also available in chip form as the HMC594.

#### Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd = +5V, Idd = 95 mA, Vdd = +6V, Idd = 100mA\*

Parameter	Min.	Тур.	Max.	Units
Frequency Range		2 - 4		GHz
Gain	7	10		dB
Gain Variation Over Temperature		0.015		dB/ °C
Noise Figure		3	4	dB
Input Return Loss		15		dB
Output Return Loss		17		dB
Output Power for 1 dB Compression (P1dB)	18	21		dBm
Saturated Output Power (Psat)		22		dBm
Output Third Order Intercept (IP3)		36		dBm
Supply Current (Idd)		100	130	mA

\*Adjust Vgg between -1.5V to -0.5V to achieve Idd = 100mA typical for 6V or Idd = 95mA typical for 5V.

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AMPLIFIER, 2 - 4 GHz





#### Broadband Gain & Return Loss [1]



Input Return Loss vs. Temperature [1]



P1dB vs. Temperature [1]



[1] Typical response for 5V and 6V Vdd



GaAs PHEMT MMIC LOW NOISE

#### Output Return Loss vs. Temperature [1]



Psat vs. Temperature [1]



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#### Power Compression @ 3 GHz, 6V



Output IP3 vs. Temperature [1]



**Reverse Isolation vs. Temperature**<sup>[1]</sup>





GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2 - 4 GHz

Power Compression @ 3 GHz, 5V

25 Pout (dBm), GAIN (dB), PAE (%) 20 Gain PAE 15 10 5 0 0 2 6 10 12 14 -10 -8 -6 -2 4 8 16 -4 INPUT POWER (dBm)

**Reverse Isolation vs. Temperature**<sup>[1]</sup>



Gain, Power & OIP3 vs. Supply Voltage @ 3 GHz



AMPLIFIERS - LOW NOISE - SM

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#### GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2 - 4 GHz

#### Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	7V	
RF Input Power (RFIN)(Vdd = +6V)	+15 dBm	
Channel Temperature	175 °C	
Continuous Pdiss (T = 85 °C) (derate 10 mW/°C above 85 °C)	0.9 W	
Thermal Resistance (channel to ground paddle)	100 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	

#### Typical Supply Current vs. Vdd

Vdd (V)	ldd (mA)
+5.5	97
+6.0	100
+6.5	103

Note: Amplifier will operate over full voltage range shown above



# **OBSERVE HANDLING PRECAUTIONS**

#### **Outline Drawing**





NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER Ni.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC594LC3B	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H594 XXXX

[1] Max peak reflow temperature of 260 °C [2] 4-Digit lot number XXXX

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# ROHS

#### GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2 - 4 GHz

#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic	
1, 3, 7, 9	GND	Package bottom must also be connected to RF/DC ground		
2	RFIN	This pin is AC coupled and matched to 50 Ohms.		
4, 6 10, 12	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.		
5	Vgg	Gate supply voltage for the amplifier. Adjust to achieve Idd= 100mA. External bypass capacitors are required.	Vgg	
8	RFOUT	This pin is AC coupled and matched to 50 Ohms.		
11	Vdd	Power Supply Voltage for the amplifier. External bypass capacitors are required.	Vdd 	

#### **Application Circuit**

Component	Value
C1, C4	100 pF
C2, C5	1,000 pF
C3, C6	2.2 µF



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#### GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2 - 4 GHz



#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 109712 [1]

Item	Description
J1 - J2	SRI SMA Connector
J3 - J6	DC Pin
C1 - C2	100 pF Capacitor, 0402 Pkg.
C3 - C4	1000 pF Capacitor, 0603 Pkg.
C5 - C6	2.2 µF Capacitor, Tantalum
U1	HMC594LC3B Amplifier
PCB [2]	109710 Evaluation PCB, 10 mils

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.